



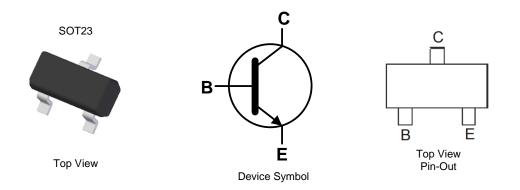
25V NPN SMALL SIGNAL TRANSISTOR IN SOT23

#### **Features**

- BV<sub>CEO</sub> > 25V
- I<sub>C</sub> = 200mA High Collector Current
- Complementary PNP Type: MMBT4126
- Ideal for Medium Power Amplification and Switching
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
  Solderable per MIL-STD-202, Method 208 
  @3
- Weight: 0.008 grams (Approximate)



## Ordering Information (Note 4)

Product	Status	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MMBT4124-7-F	Active	AEC-Q101	K1B	7	8	3,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

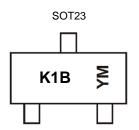
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**

Notes:



 $\begin{array}{l} \mathsf{K1N} = \mathsf{Product Type Marking Code} \\ \mathsf{YM} = \mathsf{Date Code Marking} \\ \mathsf{Y or } \overline{\mathsf{Y}} = \mathsf{Year} \ (\mathsf{ex: D} = 2016) \\ \mathsf{M or } \overline{\mathsf{M}} = \mathsf{Month} \ (\mathsf{ex: 9} = \mathsf{September}) \end{array}$ 

Date Code Key

Year	2014		2015	2016		2017	2018		2019	2020		2021
Code	В		С	D		E	F		G	Н		
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	30	V
Collector-Emitter Voltage	V <sub>CEO</sub>	25	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Collector Current	Ι <sub>C</sub>	200	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)		310	mW	
	(Note 6)	P <sub>D</sub>	350	IIIVV	
Thermal Desistance, Junction to Ambient	(Note 5)	P	403	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>θJA</sub>	357	°C/VV	
Thermal Resistance, Junction to Leads (Note 7)		R <sub>θJL</sub>	350	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 to +150	°C		

## ESD Ratings (Note 8)

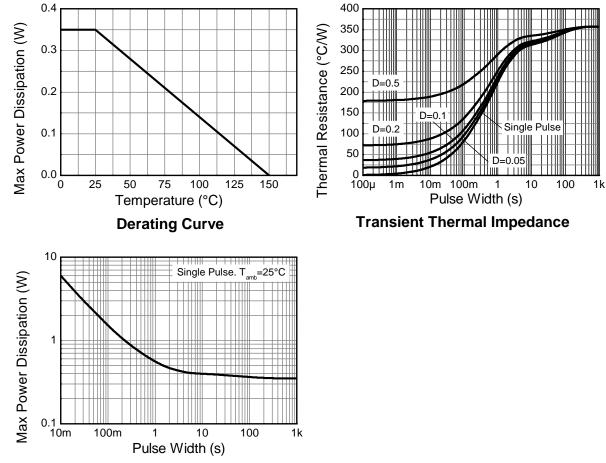
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air Notes: conditions whilst operating in a steady-state. 6. Same as Note 5, except the device is mounted on 15 mm x 15mm 1oz copper.

Thermal resistance from junction to solder-point (at the end of the leads).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



## **Thermal Characteristics and Derating Information**



**Pulse Power Dissipation** 



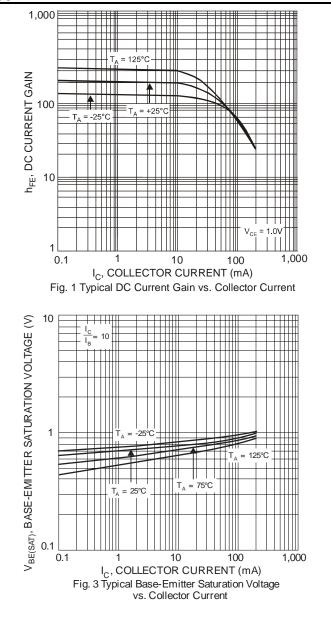
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

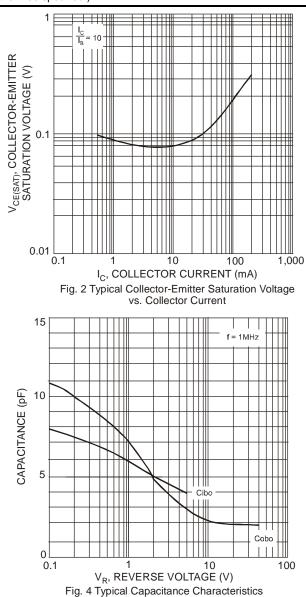
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS				•	
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	30	-	V	$I_{\rm C} = 10 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	25	-	V	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	5.0	-	V	$I_{\rm E} = 10 \mu A, I_{\rm C} = 0$
Collector-Base Cut-off Current	I <sub>CBO</sub>	-	50	nA	$V_{CB}=20V, I_{E}=0$
Emitter Base Cut-off Current	I <sub>EBO</sub>	-	50	nA	$V_{EB}=3.0V, I_{C}=0$
ON CHARACTERISTICS (Note 9)					·
DC Current Gain	h <sub>FE</sub>	120	360		$I_{C} = 2mA, V_{CE} = 1.0V$
		60	-	-	$I_{C} = 50 \text{mA}, V_{CE} = 1.0 \text{V}$
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	-	0.30	V	$I_{\rm C} = 50 {\rm mA}, I_{\rm B} = 5.0 {\rm mA}$
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	-	0.95	V	$I_{\rm C} = 50 {\rm mA}, I_{\rm B} = 5.0 {\rm mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	Cobo	-	4.0	pF	$V_{CB} = 5.0V$ , f = 1.0MHz, I <sub>E</sub> = 0
Input Capacitance	C <sub>ibo</sub>	-	8.0	pF	$V_{EB} = 0.5V$ , f = 1.0MHz, $I_{C} = 0$
Small Signal Current Gain	h <sub>fe</sub>	120	480	-	$V_{CE} = 1.0V, I_{C} = 2.0mA, f = 1.0kHz$
Current Gain-Bandwidth Product	f⊤	300	-	MHz	$\label{eq:Vce} \begin{array}{l} V_{CE} = 20V, \ I_C = 10mA, \\ f = 100MHz \end{array}$

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

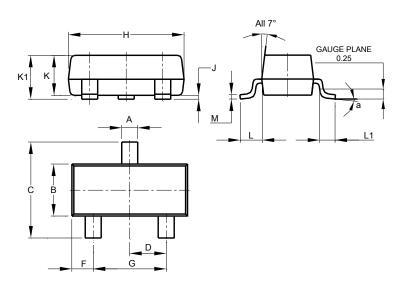






## **Package Outline Dimensions**

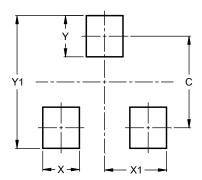
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SO	T23	
Dim	Min	Max	Тур
Α	0.37	0.51	0.40
В	1.20	1.40	1.30
С	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
Н	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
М	0.085	0.150	0.110
а	0°	8°	
All	Dimens	ions in	mm

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)			
С	2.0			
Х	0.8			
X1	1.35			
Y	0.9			
Y1	2.9			



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